SLOS437K - APRIL 2004 - REVISED OCTOBER 2010

# DUAL OPERATIONAL AMPLIFIERS WITH INTERNAL REFERENCE

Check for Samples: TL103W, TL103WA

### **FEATURES**

#### OPERATIONAL AMPLIFIER

- Low Offset Voltage Max of:
  - TL103WA...3 mV (25°C) and 5 mV (Full Temperature)
  - TL103W...4 mV (25°C) and 5 mV (Full Temperature)
- Low Supply Current...350 μA/Channel (Typ)
- Unity Gain Bandwidth...0.9 MHz (Typ)
- Input Common-Mode Range Includes GND
- Large Output-Voltage Swing...
   0 V to V<sub>CC</sub> 1.5 V
- Wide Supply-Voltage Range...3 V to 32 V
- 2-kV ESD Protection (HBM)

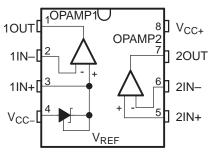
#### VOLTAGE REFERENCE

- Fixed 2.5-V Reference
- Tight Tolerance Max of:
  - TL103WA...0.4% (25°C) and 0.8% (Full Temperature)
  - TL103W . . . 0.7% (25°C) and 1.4% (Full Temperature)
- Low Temperature Drift...7 mV (Typ) Over Operating Temperature Range
- Wide Sink-Current Range . . .0.5 mA (Typ) to 100 mA
- Output Impedance...0.2 Ω (Typ)

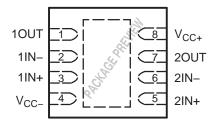
### TYPICAL APPLICATIONS

- Battery Chargers
- Switch-Mode Power Supplies
- Linear Voltage Regulation
- Data-Acquisition Systems

### D (SOIC) PACKAGE (TOP VIEW)



### DRJ (QFN) PACKAGE (TOP VIEW)



NOTE: Exposed thermal pad is connected internally to  $V_{CC-}$  via die attach.

### DESCRIPTION/ORDERING INFORMATION

The TL103W and TL103WA combine the building blocks of a dual operational amplifier and a fixed voltage reference – both of which often are used in the control circuitry of both switch-mode and linear power supplies. OPAMP1 has its noninverting input internally tied to a fixed 2.5-V reference, while OPAMP2 is independent, with both inputs uncommitted.

For the A grade, especially tight voltage regulation can be achieved through low offset voltages for both operational amplifiers (typically 0.5 mV) and tight tolerances for the voltage reference (0.4% at 25°C and 0.8% over operating temperature range).

The TL103W and TL103WA are characterized for operation from -40°C to 105°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### **ORDERING INFORMATION**

T <sub>A</sub>	MAX V <sub>IO</sub> AND V <sub>REF</sub> TOLERANCE (25°C)	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
		QFN (DRJ)	Reel of 1000	TL103WAIDRJR	PREVIEW
	A grade 3 mV, 0.4%	COIC (D)	Tube of 75	TL103WAID	74.00\\\\
400C to 4050C		SOIC (D)	Reel of 2500	TL103WAIDR	Z103WA
–40°C to 105°C		QFN (DRJ)	Reel of 1000	TL103WIDRJR	PREVIEW
	Standard grade 4 mV. 0.7%	SOIC (D)	Tube of 75	TL103WID	74.02\\\
	4 IIIV, 0.7 76	SOIC (D)	Reel of 2500	TL103WIDR	Z103W

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

## **Typical Application Circuit**

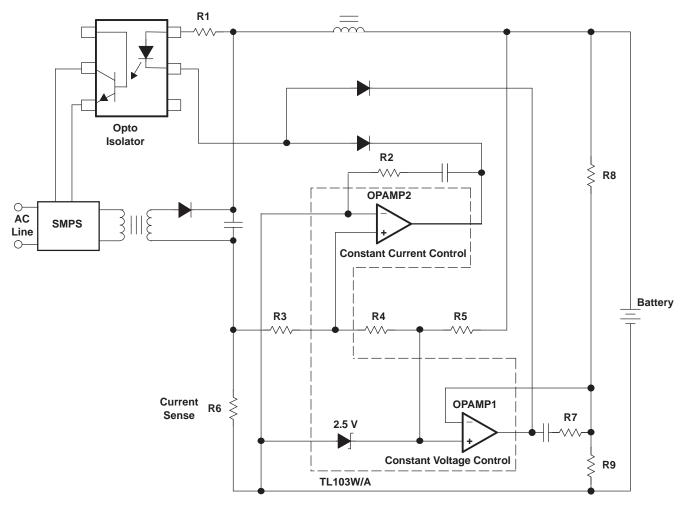


Figure 1. TL103W/A in a Constant-Current and Constant-Voltage Battery Charger

## Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage			36	V	
$V_{\text{ID}}$	Operational amplifier input differential voltage			36	V	
VI	Operational amplifier input voltage range		-0.3	36	V	
I <sub>KA</sub>	Voltage reference cathode current			100	mA	
0	Park and the good from the con-	D package <sup>(2)</sup> (3)		97	00/11/	
$\theta_{JA}$	Package thermal impedance	DRJ package <sup>(2) (4)</sup>		TBD	°C/W	
TJ	Maximum junction temperature			150	°C	
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
- (2) Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Selecting the maximum of 150°C can affect reliability.
- (3) The package thermal impedance is calculated in accordance with JESD 51-7.
- (4) The package thermal impedance is calculated in accordance with JESD 51-5.

### **Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{\text{IN}}$	Supply voltage	3	32	V
I <sub>K</sub>	Cathode current	1	100	mA
T <sub>A</sub>	Operating free-air temperature	-40	105	°C



# OPAMP1, Operational Amplifier With Noninverting Input Connected to the Internal $V_{\text{REF}}$ Electrical Characteristics

 $V_{CC+} = 5 V$ ,  $V_{CC} = GND$ ,  $T_A = 25$ °C (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
		TL103W	V -0.V	25°C		1	4		
M	land offert veltage	ILIUSVV	$V_{icm} = 0 V$	Full range			5	\/	
$V_{10}$	Input offset voltage	TI 402\\/	V 0 V	25°C		0.5	3	mV	
		TL103WA	V <sub>icm</sub> = 0 V	Full range			5		
$\alpha V_{\text{IO}}$	Input offset-voltage d	rift		25°C		7		μV/°C	
$I_{IB}$	Input bias current (ne	gative input)		25°C		20		nA	
A <sub>VD</sub>	Large-signal voltage	gain	$V_{CC+} = 15 \text{ V}, R_L = 2 \text{ k}\Omega, V_{icm} = 0 \text{ V}$	25°C		100		V/mV	
k <sub>SVR</sub>	Supply-voltage rejecti	ion ratio	V <sub>CC+</sub> = 5 V to 30 V, V <sub>icm</sub> = 0 V	25°C	65	100		dB	
I <sub>O(source)</sub>	Output source curren	t	$V_{CC+} = 15 \text{ V}, V_{O} = 2 \text{ V}, V_{id} = 1 \text{ V}$	25°C	20	40		mA	
I <sub>SC</sub>	Short circuit to GND		V <sub>CC+</sub> = 15 V	25°C		40	60	mA	
I <sub>O(sink)</sub>	Output ainly aureant		$V_{CC+} = 15 \text{ V}, V_{O} = 2 \text{ V}, V_{id} = -1 \text{ V}$	25°C	10	12		mA	
	Output sink current		$V_{CC+} = 15 \text{ V}, V_{O} = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	25 0	12	50		μΑ	
			$V_{CC} = 30 \text{ V}, R_1 = 2 \text{ k}\Omega$	25°C	26	27			
V	High-level output volt		$V_{CC} = 30 \text{ V}, \text{ R}_{L} = 2 \text{ K}\Omega$	Full range	26			V	
V <sub>OH</sub>	High-level output voit	aye	$V_{CC} = 30 \text{ V}, R_1 = 10 \text{ k}\Omega$	25°C	27	28		V	
			V <sub>CC</sub> = 50 V, K <sub>L</sub> = 10 KΩ	Full range	27				
M	Low lovel output valte		B 4010	25°C		5	20	mV	
V <sub>OL</sub>	Low-level output volta	age	$R_L = 10 \text{ k}\Omega$	Full range			20	IIIV	
SR	Slew rate at unity gain	n	$V_{CC+} = 15 \text{ V}, C_L = 100 \text{ pF},$ $R_L = 2 \text{ k}\Omega, V_I = 0.5 \text{ V} \text{ to 2 V}, \text{ unity gain}$	25°C	0.2	0.4		V/μs	
GBW	Gain bandwidth produ	uct	$V_{CC+} = 30 \text{ V}, V_I = 10 \text{ mV}, \\ C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega, f = 100 \text{ kHz}$	25°C	0.5	0.9		MHz	
THD	Total harmonic distor	tion	$V_{CC+} = 30 \text{ V}, V_O = 2 \text{ V}_{pp}, C_L = 100 \text{ pF},$ $R_L = 2 \text{ k}\Omega, f = 1 \text{ kHz}, A_V = 20 \text{ dB}$	25°C		0.02		%	

## **OPAMP2**, Independent Operational Amplifier Electrical Characteristics

 $V_{CC+} = 5 \text{ V}, V_{CC} = \text{GND}, V_{O} = 1.4 \text{ V}, T_{A} = 25^{\circ}\text{C}$  (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
		TI 400\\	V 0 V	25°C		1	4		
.,		TL103W	$V_{icm} = 0 V$	Full range			5	.,	
$V_{IO}$	Input offset voltage	TI 400\444		25°C		0.5	3	mV	
		TL103WA	$V_{icm} = 0 V$	Full range			5		
$\alpha V_{IO}$	Input offset voltage d	rift		25°C		7		μV/°C	
	land effect comment			25°C		2	75	A	
I <sub>IO</sub>	Input offset current			Full range			150	nA	
	Leaved Idda a summer			25°C		20	150	0	
I <sub>IB</sub>	Input bias current			Full range			200	nA	
^	Laura Sarahaskana		$V_{CC+} = 15 \text{ V}, R_L = 2 \text{ k}\Omega,$	25°C	50	100		\ //\ /	
$A_{VD}$	Large-signal voltage	gain	V <sub>O</sub> = 1.4 V to 11.4 V	Full range	25			V/mV	
k <sub>SVR</sub>	Supply-voltage reject	ion ratio	V <sub>CC+</sub> = 5 V to 30 V	25°C	65	100		dB	
	land a same a		V <sub>CC+</sub> = 30 V <sup>(1)</sup>	25°C	0		V <sub>CC+</sub> – 1.5		
$V_{ICR}$	Input common-mode	voitage range	Strage range VCC+ = 50 V F		0		V <sub>CC+</sub> – 2	V	
OMPD	0	C		25°C	70	85		-ID	
CMRR	Common-mode rejec	tion ratio		Full range	60			dB	
I <sub>O(source)</sub>	Output source curren	t	V <sub>CC+</sub> = 15 V, V <sub>O</sub> = 2 V, V <sub>id</sub> = 1 V	25°C	20	40		mA	
I <sub>SC</sub>	Short circuit to GND		V <sub>CC+</sub> = 15 V	25°C		40	60	mA	
	Output sink summent		$V_{CC+} = 15 \text{ V}, V_O = 2 \text{ V}, V_{id} = -1 \text{ V}$	25.0	10	12		mA	
I <sub>O(sink)</sub>	Output sink current		$V_{CC+} = 15 \text{ V}, V_O = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	25°C	12	50		μΑ	
			V 20 V B 210	25°C	26	27			
	I Park James Landon de Land		$V_{CC} = 30 \text{ V}, R_L = 2 \text{ k}\Omega$	Full range	26				
V <sub>OH</sub>	High-level output volt	age	V 00 V D 10 LO	25°C	27	28		V	
			$V_{CC} = 30 \text{ V}, R_L = 10 \text{ k}\Omega$	Full range	27				
\/	Low love Landard Call		B 40 k0	25°C		5	20	mr\/	
$V_{OL}$	Low-level output volta	age	$R_L = 10 \text{ k}\Omega$	Full range			20	mV	
SR	Slew rate at unity gai	n	$\begin{split} &V_{CC+} = 15 \text{ V, } C_L = 100 \text{ pF,} \\ &R_L = 2 \text{ k}\Omega, \text{ V}_I = 0.5 \text{ V to 3 V,} \\ &\text{unity gain} \end{split}$	25°C	0.2	0.4		V/μs	
GBW	Gain bandwidth produ	uct	$V_{CC+} = 30 \text{ V}, V_I = 10 \text{ mV}, \\ C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega, \\ f = 100 \text{ kHz}$	25°C	0.5	0.9		MHz	
THD	Total harmonic distor	tion	$V_{CC+} = 30 \text{ V}, V_O = 2 \text{ V}_{pp},$ $C_L = 100 \text{ pF}, R_L = 2 \text{ k}\Omega,$ $f = 1 \text{ kHz}, A_V = 20 \text{ dB}$	25°C		0.02		%	
V <sub>n</sub>	Equivalent input noise	e voltage	$V_{CC} = 30 \text{ V}, R_S = 100 \Omega,$ f = 1 kHz	25°C		50		nV/√ <del>Hz</del>	

<sup>(1)</sup> The input common-mode voltage of either input should not be allowed to go below −0.3 V. The upper end of the common-mode voltage range is V<sub>CC+</sub> − 1.5 V, but either input can go to V<sub>CC+</sub> + 0.3 V (but ≤36 V) without damage.



## Voltage Reference Electrical Characteristics

	PARAMETER		TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
		TL103W	1 - 10 mA	25°C	2.482	2.5	2.518	
V	Deference valtage	1110300	I <sub>K</sub> = 10 mA	Full range	2.465		2.535	V
$V_{REF}$	·	TL103WA	1 10 mA	25°C	2.49	2.5	2.51	
		ILIUSWA	I <sub>K</sub> = 10 mA	Full range	2.48		2.52	
$\Delta V_{REF}$	Reference input voltage deviation over temperature range		$V_{KA} = V_{REF}$ , $I_K = 10 \text{ mA}$	Full range		7	30	mV
I <sub>min</sub>	Minimum cathode current for regulation		$V_{KA} = V_{REF}$	25°C		0.5	1	mA
z <sub>ka</sub>	Dynamic impedance <sup>(1</sup>	Dynamic impedance <sup>(1)</sup> $V_{KA} = V_{REF}, \Delta I_{K} = 1 \text{ mA to } 100 \text{ mA}, $ f < 1 kHz		25°C		0.2	0.5	Ω

$$|z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$$

# **Total Device Electrical Characteristics**

	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	UNIT
	Total supply current,	V <sub>CC+</sub> = 5 V, No load	Full rongs		0.7	1.2	A
ICC	excluding cathode-current reference	V <sub>CC+</sub> = 30 V, No load	Full range			2	mA

Submit Documentation Feedback

<sup>(1)</sup> The dynamic impedance is defined as

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### **REVISION HISTORY**

Cł	hanges from Revision J (September 2010) to Revision K	Page
•	Changed topside marking to fix typo Z103WQ to Z103WA	2



6-Oct-2010

### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
TL103WAID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TL103WAIDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TL103WAIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Contact TI Distributor or Sales Office
TL103WAIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TL103WAIDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TL103WAIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TL103WID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
TL103WIDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
TL103WIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples
TL103WIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TL103WIDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TL103WIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



### PACKAGE OPTION ADDENDUM

6-Oct-2010

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

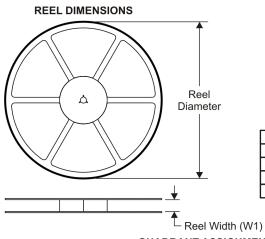
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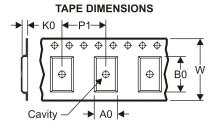
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## PACKAGE MATERIALS INFORMATION

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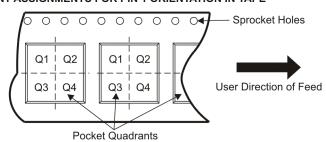
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

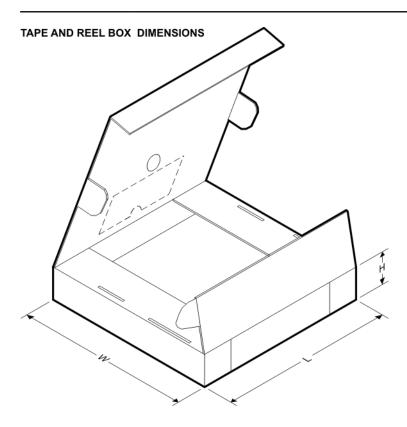


### \*All dimensions are nominal

1	7 til dillionolollo alo nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	TL103WAIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
	TL103WIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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### \*All dimensions are nominal

Device	Package Type	e Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
TL103WAIDR	SOIC	D	8	2500	340.5	338.1	20.6
TL103WIDR	SOIC	D	8	2500	340.5	338.1	20.6

## D (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



## D (R-PDSO-G8)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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